

Hiroyuki Litta et al. - U.S. Serial No. 09/883,216

REMARKS

The above amendment is made to clarify claim 4. The Examiner is requested to consider this amendment prior to an action on the merits.

Please charge any fee associated with the filing of this paper to our Deposit Account No. 19-0733.

Respectfully submitted,

By: 

Joseph M. Potenza

Registration No. 28,175 

BANNER & WITCOFF, LTD.  
1001 G Street, N.W., 11<sup>th</sup> Floor  
Washington, D.C. 20001  
(202) 508-9100  
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**Marked Up Version of Amendment Showing Changes**

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**In the Claims:**

Claim 4 has been amended as follows:

4. (Amended) The semiconductor device according to claim 1, further comprising:

a second insulation film formed above the space region, the second insulation film being different from the first insulation film; and

a third insulation film formed on a sidewall of the groove section, the third insulation film being different from the first and second insulation films.